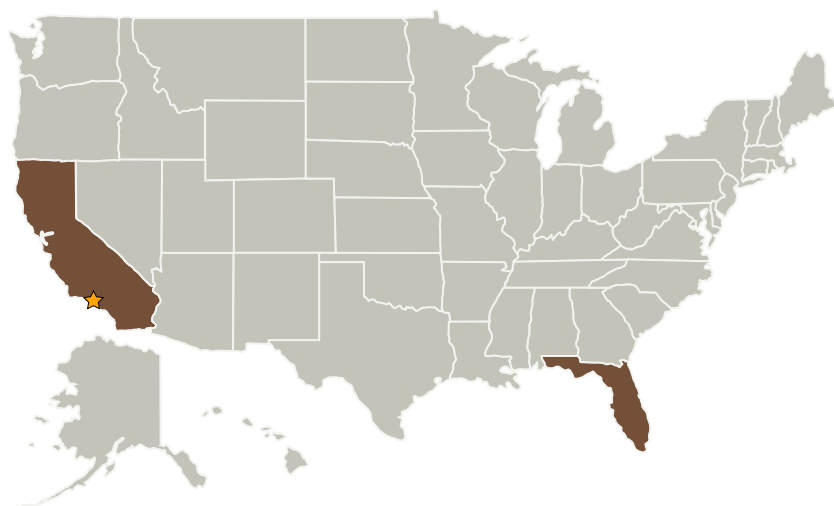


Laser Doping for Silicon Carbide Device Fabrication, Phase I

Completed Technology Project (2003 - 2003)



Primary U.S. Work Locations and Key Partners



Organizations Performing Work	Role	Type	Location
★ Jet Propulsion Laboratory (JPL)	Lead Organization	NASA Center	Pasadena, California
AppliCote Associates, LLC	Supporting Organization	Industry	Lake Mary, Florida

Primary U.S. Work Locations

California	Florida
------------	---------



Laser Doping for Silicon Carbide Device Fabrication, Phase I

Table of Contents

Primary U.S. Work Locations and Key Partners	1
Organizational Responsibility	1
Project Management	2
Technology Areas	2

Organizational Responsibility

Responsible Mission Directorate:

Space Technology Mission Directorate (STMD)

Lead Center / Facility:

Jet Propulsion Laboratory (JPL)

Responsible Program:

Small Business Innovation Research/Small Business Tech Transfer

Laser Doping for Silicon Carbide Device Fabrication, Phase I

Completed Technology Project (2003 - 2003)



Project Management

Program Director:

Jason L Kessler

Program Manager:

Carlos Torrez

Principal Investigator:

Nathaniel Quick

Technology Areas

Primary:

- TX06 Human Health, Life Support, and Habitation Systems
 - └ TX06.3 Human Health and Performance
 - └ TX06.3.5 Food Production, Processing, and Preservation